VS-SD2000C..L Series

Vishay Semiconductors

Standard Recovery Diodes (Hockey PUK Version), 2100 A



DO-200AB (B-PUK)

PRODUCT SUMMARY					
I _{F(AV)} 2100 A					
Package	DO-200AB (B-PUK)				
Circuit configuration	Single Diode				

FEATURES

- Wide current range
- High voltage ratings up to 1000 V
- High surge current capabilities
- Diffused junction
- Hockey PUK version
- Case style DO-200AB (B-PUK)
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Converters
- Power supplies
- High power drives
- Auxiliary system supplies for traction applications

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
1		2100	A		
I _{F(AV)}	T _{hs}	55	°C		
1		3900	A		
I _F (RMS)	T _{hs}	25	°C		
I _{FSM}	50 Hz	23 900			
	60 Hz	25 000	A		
l ² t	50 Hz	2857	1.42-		
1-1	60 Hz	2608	kA ² s		
V _{RRM}	Range	400 to 1000	V		
TJ		-40 to 180	°C		

ELECTRICAL SPECIFICATIONS

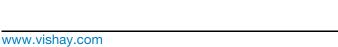
VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 180 °C mA				
	04	400	500					
VS-SD2000CL 08		800	900	60				
	10	1000	1100					

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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current		180° conducti	on, half sine wa	ve	2100 (1040)	D (1040) A
at heatsink temperature	I _{F(AV)}	Double side (s	single side) coole	ed	55 (85)	°C
Maximum RMS forward current	I _{F(RMS)}	25 °C heatsinl	k temperature do	ouble side cooled	3900	
		t = 10 ms	No voltage		23 900	A
Maximum peak, one-cycle forward,	l	t = 8.3 ms	reapplied		25 000	
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM} reapplied	Sinusoidal half wave, initial T _J = T _J maximum	20 100	
		t = 8.3 ms			21 000	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage reapplied		2857	kA ² s
		t = 8.3 ms			2608	
		t = 10 ms	100 % V _{RRM} reapplied		2020	
		t = 8.3 ms			1844	
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied			28 570	kA²√s
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), T _J = T _J maximum			0.74	V
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi x I_{F(AV)}), T_J = T_J maximum$			0.86	v
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum			0.13	mW
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}),$	T _J = T _J maximur	0.12	IIIVV	
Maximum forward voltage drop	V _{FM}	$I_{pk} = 6000 \text{ A}, T_J = T_J \text{ maximum, } t_p = 10 \text{ ms sinusoidal wave}$			1.55	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating temperature range	TJ		-40 to 180	°C	
Maximum storage temperature range	T _{Stg}		-55 to 200		
Maximum thermal resistance,	R _{thJ-hs}	DC operation single side cooled	0.073	K/W	
junction to heatsink		DC operation double side cooled	0.031	r∨ vv	
Mounting force, ± 10 %			14 700 (1500)	N (kg)	
Approximate weight			255	g	
Case style		See dimensions - link at the end of datasheet	DO-200AB	(B-PUK)	

CONDUCTION ANGLE	TEST CONDITIONS	UNITS						
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS		
180°	0.009	0.009	0.006	0.006		K/W		
120°	0.011	0.011	0.011	0.011				
90°	0.014	0.014	0.015	0.015	$T_J = T_J maximum$			
60°	0.020	0.020	0.021	0.021				
30°	0.036	0.036	0.036	0.036				

Note

The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

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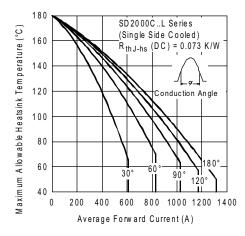


Fig. 1 - Current Ratings Characteristics

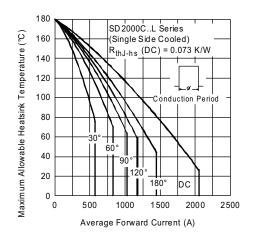


Fig. 2 - Current Ratings Characteristics

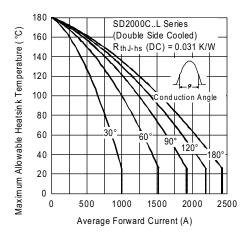


Fig. 3 - Current Ratings Characteristics

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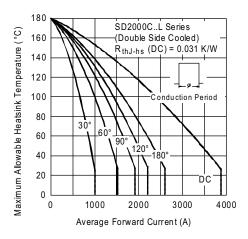


Fig. 4 - Current Ratings Characteristics

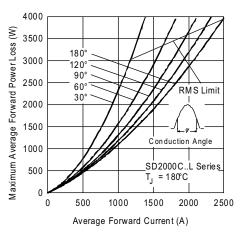


Fig. 5 - Forward Power Loss Characteristics

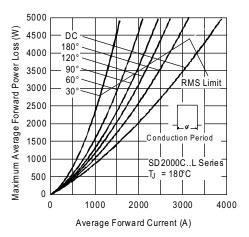


Fig. 6 - Forward Power Loss Characteristics

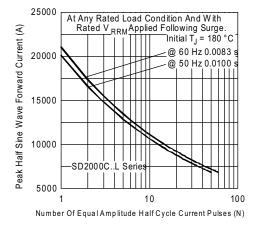
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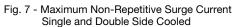
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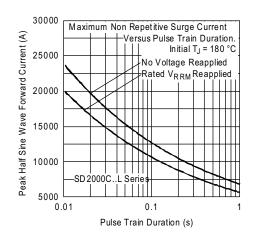
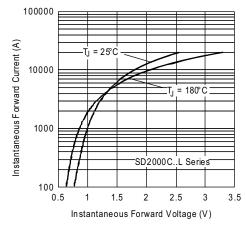
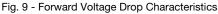
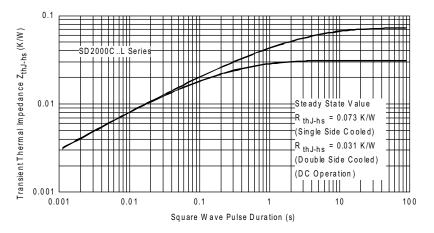


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled









ORDERING INFORMATION TABLE

Device code	VS-	SD	200	0	с	10	L
		(2)	(3)	(4)	(5)	6	$\overline{7}$
	<u> </u>	Vieł			\bigcirc	oduct	\bigcirc
		 Vishay Semiconductors product Diode 					
	3 -	- Essential part number					
	4 -	 0 = Standard recovery 					
	5 -	C =	Cerami	c PUK			
	6 -	Volt	age cod	le x 100	= V _{RRM}	_I (see V	oltage F
	7 -	L =	PUK ca	se DO-2	200AB (I	B-PUK)	

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95246				

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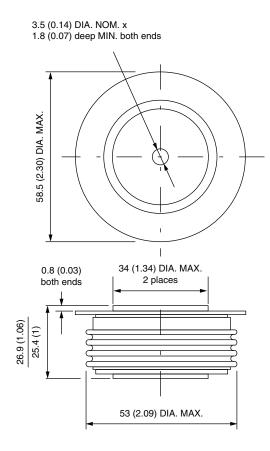


Outline Dimensions

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DO-200AB (B-PUK)

DIMENSIONS in millimeters (inches)



Quote between upper and lower pole pieces has to be considered after application of mounting force (see Thermal and Mechanical Specifications)



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